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# Light-emitting Ti<sub>2</sub>N (MXene) quantum dots: synthesis, characterization and theoretical calculations†

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MXene-based quantum dots (MQDs), which are obtained by fragmenting MXenes into a nanometer scale, can display photoluminescence (PL), suggesting light-emitting applications for bandgap-less MXenes. However, despite the diverse possible formations of MXene components, only carbide MXene-based MQDs have been reported to emit light. In this study, we synthesized water-soluble MQDs with an average diameter of 3.14 nm using the titanium nitride (Ti<sub>2</sub>N) MXene. Ti<sub>2</sub>N MQDs exhibited efficient PL, with a maximum quantum yield of 7.5%, upon light absorption over the deep UV wavelength range of 400–230 nm. The density functional theory calculations and PL excitation measurements identified a bandgap of 3.8 eV and the existence of an unfulfilled band (E<sub>1</sub>) between the occupied low-energy (E<sub>0</sub>) and unoccupied high-energy (E<sub>2</sub>) bands, which induces strong absorption in deep UV energy originating from the E<sub>0</sub>–E<sub>2</sub> transition. Light-emitting nitride MQDs expand and facilitate the UV optoelectronic applications of MQDs.

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## 1. Introduction

Two-dimensional (2D) MXenes (general formula: M<sub>n+1</sub>X<sub>n</sub>T<sub>x</sub>, where M is an early transition metal, X is either C, N, or O and N, and T<sub>x</sub> is the notation of the surface-terminating functional groups, such as O, OH, F, and H)<sup>1–6</sup> have the properties of high conductivity, flexibility, and non-toxicity.<sup>1,7–10</sup> MXenes are obtained by chemically etching out A-elements from MAX phases and there are approximately 150 different types of MAX phases currently available.<sup>11</sup> Thus, MXenes with various combinations of constituting elements have been studied for energy storage devices, sensors, electromagnetic interference, solar cells, catalysis, transparent conductors, and

photothermal and plasmonic applications.<sup>1,2,6–8,12–16</sup> However, MXenes are generally absent in the bandgap and only theoretical calculations predict a very small bandgap (<0.1 V),<sup>1</sup> limiting their use in optoelectronic applications.

In 2017, Xue *et al.* obtained the Ti<sub>3</sub>C<sub>2</sub> MXene *via* a hydrothermal process. The resulting Ti<sub>3</sub>C<sub>2</sub> MXene was several nanometers in size and displayed efficient photoluminescence (PL), which originated from the quantum confinement effect.<sup>13</sup> These MXene-based quantum dots (MQDs)<sup>13,17–23</sup> have been extensively studied for applications in light-emitting diodes (LEDs), catalysis, biosensors, photothermal therapy, energy storage, and bioimaging.<sup>13,17–32</sup> While mostly carbide group MQDs have been studied so far,<sup>13,17,25,33–35</sup> nitride or carbonitride MXenes have higher expected electronic conductivity and better stability in solution than carbide MXenes<sup>3,5</sup> and are thus promising precursors of MQDs. Recently, Shao *et al.* synthesized MQDs based on the Ti<sub>2</sub>N MXene and demonstrated their biodegradability and biocompatibility; however, their light-emitting properties were not discussed.<sup>23</sup>

In this study, we report the synthesis of light-emitting Ti<sub>2</sub>N MQDs, which displayed a strong PL upon deep UV absorption down to a wavelength of 230 nm. Light emission was confirmed from both the aqueous solution and film dispersion. The PL excitation (PLE) measurements and density functional theory (DFT) calculations revealed the origins of efficient light emission and absorption in deep UV energy. Our results substantially expand the application of MQDs in UV optoelectronic devices.

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† Electronic supplementary information (ESI) available: TEM image of Ti<sub>2</sub>C MQDs (S1); fluorescence of Ti<sub>2</sub>N MQDs dispersed in water (S2); PL spectrum of Ti<sub>2</sub>N MQD solution and thin film under 375 nm laser excitation. Confocal image of thin-film Ti<sub>2</sub>N MQDs under 405 nm laser excitation. Thin-film Ti<sub>2</sub>N MQDs drop-casted on a quartz substrate illuminated with an UV (250 nm) LED (S3); plot of Ti<sub>2</sub>N MQDs' QY (%) estimation vs. excitation energy (S4); PL intensity and QY of Ti<sub>2</sub>N MQDs in 10 days (S5); PL spectra and QY of Ti<sub>2</sub>N MQDs at different pH values ranging from 2 to 12 (S6); UV-Vis absorption spectra, PL spectra and QY of Ti<sub>2</sub>N MQDs in the presence of Co<sup>2+</sup> and Mn<sup>2+</sup> ions (S7); DFT calculation of Ti<sub>2</sub>NO<sub>2</sub> MQDs with sizes of 1.5 nm and 3 nm (S8); DFT calculation of Ti<sub>2</sub>N MQDs (S9). See <https://doi.org/10.1039/d2tc00568a>

## 2. Experimental

### Materials

Ti<sub>2</sub>AlN MAX phase powder (200-mesh) and Ti<sub>2</sub>AlC MAX phase powder (200-mesh) were purchased from Shanghai Xinglu Chemical Technology Co. Ltd, Shanghai, China. Hydrochloric acid (HCl) and potassium fluoride (KF) were purchased from Merck Korea, Seoul, Republic of Korea. All other chemicals were of analytical grade and directly used as is.

### Sample preparation

The Ti<sub>2</sub>N MXene was prepared by etching the Al layer of the Ti<sub>2</sub>AlN MAX phase using a mixture of HCl and KF powder.<sup>5,23</sup> Specifically, 6 M HCl (100 mL) was added to KF powder (6 g) and continuously stirred until the solution was well mixed. The solution (20 mL) was added to the Ti<sub>2</sub>AlN MAX phase powder and left at room temperature for 3 h to selectively etch the Al layer. Afterward, the solution was heated at 40 °C with bath sonication (1 h) to promote intercalation, which aided the exfoliation process. The obtained suspension of Ti<sub>2</sub>N MXene was washed multiple times using deionized water and centrifuged (12 000 rpm) for 20 min to remove the soluble fluorides. Fluoride removal was performed until the pH was close to 6 to obtain the Ti<sub>2</sub>N MXene powder. Ti<sub>2</sub>N MQDs were synthesized from Ti<sub>2</sub>N MXene powder based on a previous procedure for synthesizing carbide MQDs by adjusting chemical concentrations.<sup>13</sup> Specifically, the Ti<sub>2</sub>N MXene powder (1.1 g) was dispersed in deionized water (10 mL) and added to a 50 mL Teflon-lined stainless-steel autoclave. Ammonium hydroxide (NH<sub>4</sub>OH) was added slowly until the solution reached a pH of 10. Then, the autoclave was kept in a vacuum oven at 100 °C for 6 h. The resulting mixture was centrifuged at 10 000 rpm for 20 min and the supernatant of Ti<sub>2</sub>N MQDs was collected. Ti<sub>2</sub>C MQDs were prepared using the same procedure as that used for synthesizing Ti<sub>2</sub>N MQDs. Ti<sub>2</sub>C MXene precursor was obtained from the Ti<sub>2</sub>AlC MAX phase with 10% HF as the etchant.

### Structural characterization

The structural characterization of powder X-ray diffraction (XRD) was performed using an X-ray diffractometer (D2 Phaser, Bruker). The images of the exfoliated layers of Ti<sub>2</sub>N and Ti<sub>2</sub>N MXene were obtained using scanning electron microscopy (SEM) (JSM-7600F, JEOL) and the etching of Al was confirmed using energy-dispersive X-ray spectroscopy (EDS) (X-Max, Oxford Instrument). The morphologies of the Ti<sub>2</sub>N MQDs were further analyzed using high-resolution transmission electron microscopy (HRTEM) (JEM-3010, JEOL) and atomic force microscopy (AFM) (XE-120, Park Systems).

### Optical characterization

The vibration modes and crystal structures of the Ti<sub>2</sub>N MXene-based samples were determined using a Raman confocal microscope (alpha300 SR, WITec GmbH). The UV-Vis absorption and PL spectra of the Ti<sub>2</sub>N MQD solutions were analyzed using an absorption spectrometer (Optizen, K Lab) and a fluorescence spectrophotometer (Cary Eclipse, Agilent), respectively. A thin

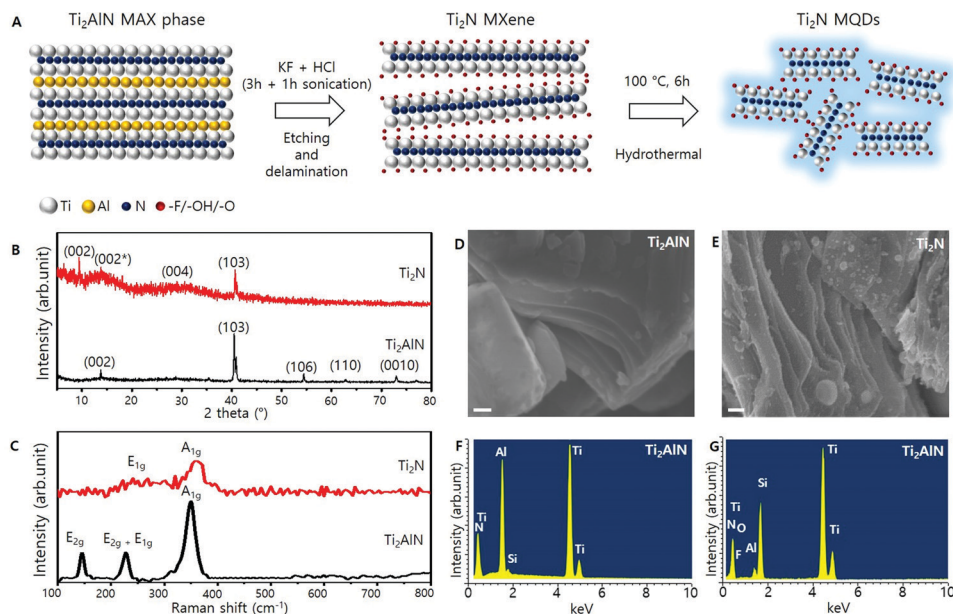
film of Ti<sub>2</sub>N MQDs was prepared by drop-casting on top of a quartz substrate, and the confocal PL was measured using a lab-made laser confocal microscope combined with a spectrometer. The laser light was focused using an objective lens (100×, 0.95 NA), and the scattered light was collected using the same objective lens and then guided to a 50 cm long monochromator equipped with a cooled charge-coupled device (CCD) (PIXIS 400, Princeton Instruments). A diode laser with an excitation wavelength of 405 nm was employed for confocal PL measurements. For quantum yield (QY) measurements, a commercial QY spectrometer (Quantaaurus-QY, Hamamatsu Photonics) and a lab-made QY measurement system, which consisted of an integrating sphere (819C-SL-3.3, Newport) combined with a spectrometer equipped with a CCD (PIXIS 400, Princeton Instruments), were used and Rhodamine 6G (R6G) was used as the reference.<sup>36</sup> Epifluorescence images were captured using an electron-multiplying CCD (EMCCD) camera (Photon MAX 512, Princeton Instruments) cooled to -70 °C. A mercury halide lamp was used as the light source and a 430 nm dichroic mirror was used to send the light into the sample through the objective lens. The light was then collected into the objective lens and a 450 nm long-pass filter was used to separate the emission from the light source.

## 3. Results and discussion

### Synthesis and structural analysis of the Ti<sub>2</sub>N MXene

The synthesis of light-emitting Ti<sub>2</sub>N MQDs is schematically presented in Fig. 1A (details are provided in the Methods section). The Ti<sub>2</sub>N MXene was obtained by chemically etching the Al layer of the Ti<sub>2</sub>AlN MAX phase, followed by a hydrothermal method, to produce the light-emitting Ti<sub>2</sub>N MQDs. The XRD results for the Ti<sub>2</sub>N MXene and Ti<sub>2</sub>AlN are presented in Fig. 1B. First, we note that most of the characteristic XRD peaks of Ti<sub>2</sub>AlN MAX phases, such as the (106), (110), and (0010) peaks, disappeared in the Ti<sub>2</sub>N XRD spectrum. Furthermore, Ti<sub>2</sub>N displayed the broadening of the (002) peak (denoted as (002\*) here) and the emergence of a new (002) peak at 9.52°, which indicates that the Al layer was mostly removed from the Ti<sub>2</sub>AlN MAX phase, expanding the distance between the Ti<sub>2</sub>N layers. The small upshift of the (103) peak is also attributed to the expansion of the Ti<sub>2</sub>N layers along the (002) plane.<sup>37</sup> A broad peak at around 30° is the reflection from the (004) plane, the presence of which is consistent with previous XRD results of the Ti<sub>2</sub>N MXene.<sup>5</sup>

Fig. 1C illustrates the Raman spectra of Ti<sub>2</sub>AlN and the Ti<sub>2</sub>N MXene. The Raman spectrum of the Ti<sub>2</sub>AlN samples (black curve) exhibited three Raman modes at 146, 224.4, 228.4, and 349.9 cm<sup>-1</sup>, which were identified as E<sub>2g</sub>, E<sub>2g</sub> + E<sub>1g</sub>, and A<sub>1g</sub> modes, respectively.<sup>5</sup> The Raman spectrum of the Ti<sub>2</sub>N MXene sample (red curve) showed peaks at 250.4 and 359.7 cm<sup>-1</sup> which can be assigned to E<sub>1g</sub> and A<sub>1g</sub> modes, originating from in-plane and out-of-plane vibrations, respectively, concerning the Ti atomic planes. The absence of the E<sub>2g</sub> mode at 146 cm<sup>-1</sup> (generated from Ti–Al bonding) ensured the removal of Al from



**Fig. 1** (A) Schematic of the synthesis of  $\text{Ti}_2\text{N}$  MXene-based quantum dots (MQDs). (B) XRD spectra of the  $\text{Ti}_2\text{AlN}$  MAX phase and  $\text{Ti}_2\text{N}$  MXene. (C) Raman spectra of  $\text{Ti}_2\text{AlN}$  and  $\text{Ti}_2\text{N}$ . (D) SEM image of  $\text{Ti}_2\text{AlN}$  (scale bar = 100 nm). (E) SEM image of  $\text{Ti}_2\text{N}$  (scale bar = 100 nm). (F) EDS spectrum of the  $\text{Ti}_2\text{AlN}$  MAX phase. G. EDS spectrum of the  $\text{Ti}_2\text{N}$  MXene.

$\text{Ti}_2\text{AlN}$  during chemical etching. Thus, the Raman studies confirmed the successful etching of Al atoms from  $\text{Ti}_2\text{AlN}$  and the formation of the  $\text{Ti}_2\text{N}$  MXene.

The surface morphologies of  $\text{Ti}_2\text{AlN}$  and  $\text{Ti}_2\text{N}$  were analyzed by SEM and are presented in Fig. 1D and 1E, which show the compact morphology of  $\text{Ti}_2\text{AlN}$  and the delamination of the crystals by the etching process in the  $\text{Ti}_2\text{N}$  MXene, respectively. With the etched Al atoms, the layers between the MXene were readily intercalated. During the sonication process, the intercalation of water and  $\text{K}^+$  rigorously helped to exfoliate the MXene layers and avoid restacking during etching.<sup>5,23</sup> To determine the variations in the atomic percentages between the  $\text{Ti}_2\text{AlN}$  and  $\text{Ti}_2\text{N}$  MXene, EDS measurements were performed, and the results are shown in Fig. 1F and G, respectively. The relative intensity of the Al peak at 1.5 keV was significantly reduced for  $\text{Ti}_2\text{N}$  compared to  $\text{Ti}_2\text{AlN}$ . The EDS spectrum of the  $\text{Ti}_2\text{N}$  MXene also exhibited minor signals for O and F due to the terminating groups,  $-\text{OH}$ ,  $-\text{F}$  or both, that may have emerged during exfoliation, which also indicates the successful exfoliation of  $\text{Ti}_2\text{AlN}$  and formation of the  $\text{Ti}_2\text{N}$  MXene.<sup>5,23</sup>

Transmission electron microscopy (TEM) images of the  $\text{Ti}_2\text{N}$  MQDs are shown in Fig. 2A, where the average diameter was estimated to be 3.14 nm (Fig. 2C), substantially smaller than that ( $\sim 5$  nm) of previously reported  $\text{Ti}_2\text{N}$  MQDs.<sup>23</sup> The standard deviation was only 0.2 nm, showing good uniformity of diameter. We also fabricated  $\text{Ti}_2\text{C}$  MQDs *via* the same hydrothermal route as that used for  $\text{Ti}_2\text{N}$  MQD synthesis and the obtained MQDs were relatively small with a lateral size of 2.75 nm and a narrower lattice spacing of 0.16 nm, as shown in Fig. S1 (ESI<sup>†</sup>). The observed diameter and lattice spacing were consistent with those of previous carbide MQDs.<sup>13,17,38</sup> The MQDs were easily dispersed on a glass substrate, which

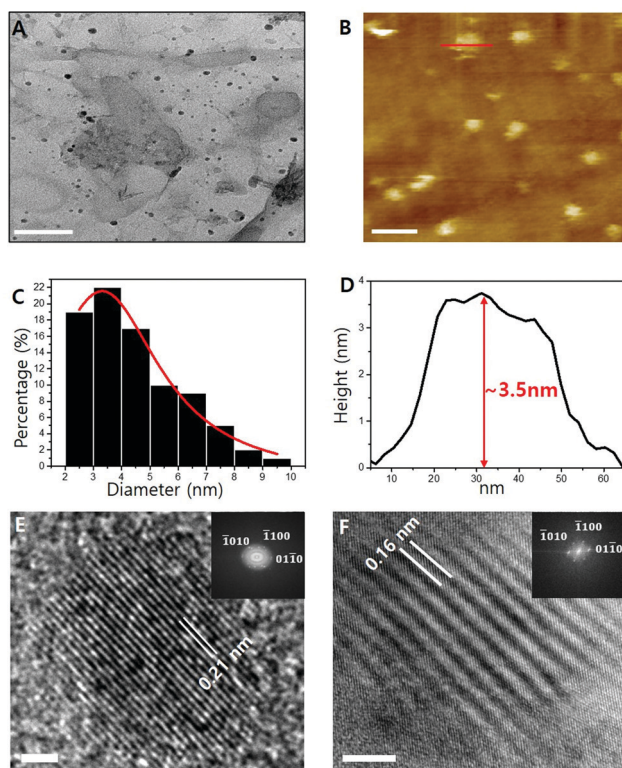
also showed an average height of  $\sim 3.5$  nm in the AFM image (Fig. 2D), consistent with the estimation of the MQD diameter by TEM.

HRTEM revealed the crystal structure of the as-prepared  $\text{Ti}_2\text{N}$  MQDs, exhibiting lattice fringes with an inner-plane spacing of 0.21 nm (Fig. 2E), corresponding to the  $(01\bar{1}0)$  facet of the MXene. This value was slightly larger than 0.16 nm for the same inner-plane spacing of  $\text{Ti}_2\text{N}$  MXene (Fig. 2F), which could be due to the effect of the intracrystalline pressure induced by the surface oxide layers of each MQD repelling each other.<sup>37,39</sup> The repelling-induced equivalent negative pressure<sup>40</sup> expands the lattice spacing with the decreasing size of the MQDs. This effect is more prevalent in which the lattice spacing is expanded because of the relatively higher surface-to-volume ratio of the  $\text{Ti}_2\text{N}$  MQDs.<sup>37,39,40</sup> The fast Fourier transform (FFT) pattern of MQDs (inset of Fig. 2E) shows that the  $\text{Ti}_2\text{N}$  MQDs retain the hexagonal structure of the pristine  $\text{Ti}_2\text{N}$  MXene. The  $\text{Ti}_2\text{N}$  MQDs maintained the  $(\bar{1}010)$ ,  $(\bar{1}100)$ , and  $(01\bar{1}0)$  facets of the  $\text{Ti}_2\text{N}$  MXene, confirming that  $\text{Ti}_2\text{N}$  MQDs mostly preserve the crystal structure of the precursor  $\text{Ti}_2\text{N}$  MXene. The low reaction temperature and surface-terminated  $-\text{NH}$  groups from the  $\text{NH}_4\text{OH}$  solution help to maintain the crystal structure of the pristine MXene, preventing the formation of  $\text{TiO}_2$  or  $\text{TiO}_2$  quantum dots.<sup>13</sup> The absence of C atoms in the chemical formula of the  $\text{Ti}_2\text{N}$  MXene, which was further confirmed by the EDS results, ruled out the formation of light-emitting carbon dots which may occur during the synthesis of carbide-group MQDs.

### Optical properties and characterization of $\text{Ti}_2\text{N}$ MQDs

Solubility in water is an important property, especially for biomedical applications.<sup>13,17,18,22,27,29,34</sup> The synthesized  $\text{Ti}_2\text{N}$





**Fig. 2** (A) TEM image of  $\text{Ti}_2\text{N}$  MQDs (scale bar = 100 nm). (B) AFM image of  $\text{Ti}_2\text{N}$  MQDs (scale bar = 50 nm). (C) Size distribution histogram of  $\text{Ti}_2\text{N}$  MQDs obtained from the TEM image. The solid line is the Gaussian fit of the distribution (A). (D) Cross-sectional height profile of  $\text{Ti}_2\text{N}$  MQDs (along the red line shown in the AFM image [B]). (E) HR-TEM image of  $\text{Ti}_2\text{N}$  MQDs (scale bar = 1 nm). (F) HR-TEM image of the  $\text{Ti}_2\text{N}$  MXene (scale bar = 5 nm). Insets of (E) and (F) are the corresponding FFT patterns of the HR-TEM images.

MQDs were all well dispersed in water. Fig. S2 (ESI<sup>†</sup>) shows the blue emission from  $\text{Ti}_2\text{N}$  MQDs dispersed in water upon illumination with an UV (250 nm) LED. Fig. 3A shows the PL spectra of the  $\text{Ti}_2\text{N}$  MQDs with varying excitation energies. Our  $\text{Ti}_2\text{N}$  MQDs displayed PL emission at an excitation wavelength of less than 280 nm. To our knowledge, this is the first demonstration of PL emission from MQDs with an excitation wavelength of less than 280 nm. A large energy difference between the excitation and emission in the range of 0.5–2 eV was previously observed for MQDs<sup>13,17,22,25,27,28,30,35</sup> and other 2D material-derived QDs<sup>41,42</sup> which have been attributed to surface state-aided exciton recombination. The PL emission peak was observed at approximately 3.0 eV with an excitation wavelength between 230 and 270 nm and then gradually redshifted with increasing excitation wavelength, similar to previously developed carbide MQDs.<sup>13,17,25,35</sup>

Absorption and PLE spectroscopy were performed on the  $\text{Ti}_2\text{N}$  MQDs and the results are shown in Fig. 3B (black curve). Two peaks at 3.9 and 5.4 eV were observed, which is consistent with the observation of two absorption edges of the absorption spectrum (red curve). The efficient absorption of UV light below 280 nm and the consequent PL emission have not been previously observed in MQDs. A previously developed carbide

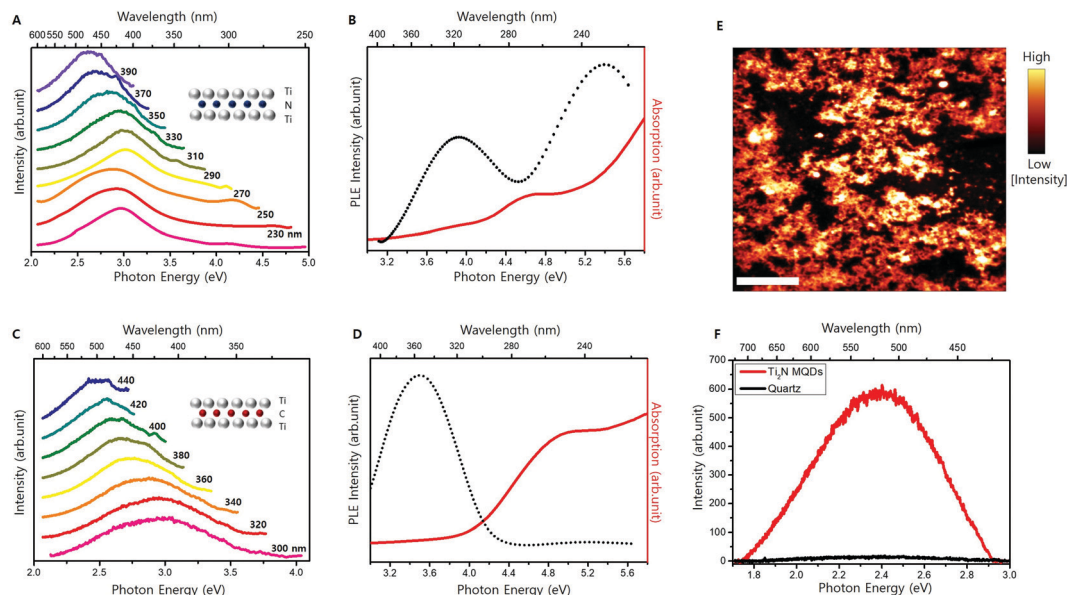
MQD,  $\text{Ti}_3\text{C}_2$  MQDs, displayed a PL emission peak at 3.0 eV, with a PLE peaking at 3.9 eV.<sup>13</sup>  $\text{V}_2\text{C}$  and  $\text{Nb}_2\text{C}$  MQDs displayed PL-emission peaks at 2.8 and 2.4 eV, respectively.<sup>34,35</sup> We prepared MQDs using the  $\text{Ti}_2\text{C}$  MXene as the main precursor and Fig. 3C shows a series of normalized PL spectra of the  $\text{Ti}_2\text{C}$  MQDs obtained with laser excitation of varying wavelengths (300–440 nm). We observed a similar gradual redshift of the PL peak with increasing excitation wavelength. The highest PL emission was obtained with a laser excitation of 350 nm, where only one peak of PLE of  $\text{Ti}_2\text{C}$  MQDs was observed at 3.5 eV (Fig. 3D), which is consistent with previous  $\text{Ti}_2\text{C}$  MQDs.<sup>38</sup> Below 300 nm, PL was too weak to be detected consistently, with only one absorption edge at approximately 4.0 eV, in contrast to the presence of two absorption edges and two PLE peaks of the  $\text{Ti}_2\text{N}$  MQDs. Our results indicate that  $\text{Ti}_2\text{N}$  MQDs are more efficient in deep UV absorption and the consequent light emission than carbide MQDs, which suggests the advantage of  $\text{Ti}_2\text{N}$  MQDs for UV applications compared to carbide MQDs.

The QY of  $\text{Ti}_2\text{N}$  MQDs was estimated using the comparative method and the highest QY was estimated to be 7.5% with 320 nm ( $\sim 3.9$  eV) excitation, where the peak was observed in the PLE (details of QY estimation and the plot of QY vs. excitation energy are given in Fig. S4, ESI<sup>†</sup>). The QY of our  $\text{Ti}_2\text{N}$  MQDs was observed to be stable for ten days in aqueous solution under ambient conditions (Fig. S5, ESI<sup>†</sup>). We dispersed the  $\text{Ti}_2\text{N}$  MQDs on a quartz substrate and observed a clear PL upon 430 nm excitation, as shown in the epifluorescence image of dispersed MQDs (Fig. 3E). The confocal scanning PL of solid dispersed  $\text{Ti}_2\text{N}$  MQDs excited with a 405 nm wavelength laser was performed, and the PL intensity map is shown in Fig. S3 (ESI<sup>†</sup>).

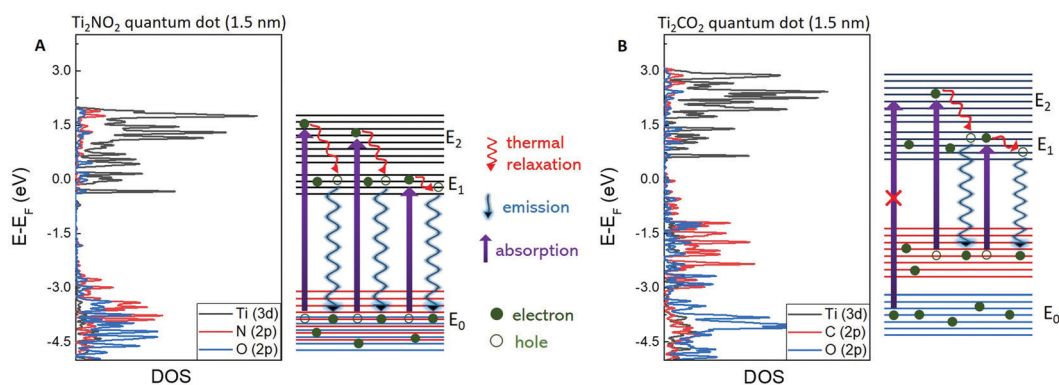
Fig. 3F shows a PL peak at 2.4 eV, with slightly less energy than the PL peak at 2.6 eV obtained from the solution-dispersed  $\text{Ti}_2\text{N}$  MQDs at 400 nm excitation. This discrepancy in the PL peak position is attributed to the variation of the dielectric environment, where the PL peak energy tends to decrease in the solid form compared to the polar solvent.<sup>43,44</sup> To the best of our knowledge, this is the first report of PL emission and the spectra of solid dispersed MQDs. Our developed  $\text{Ti}_2\text{N}$  MQDs can be excited and emitted in the form of a thin film with a wide range of excitation wavelengths. Our  $\text{Ti}_2\text{N}$  MQDs demonstrated high tolerance in pH variation and the PL and QY were virtually constant for the pH range of 2–12 (Fig. S6, ESI<sup>†</sup>). On contrary, the PL intensity of  $\text{Ti}_2\text{N}$  MQDs was drastically quenched when solutions of  $\text{Co}^{2+}$  or  $\text{Mn}^{2+}$  ions were added (Fig. S7, ESI<sup>†</sup>), exhibiting an outstanding capability to detect environmentally harmful heavy metal ions.

### Origins of the light absorption and emission of $\text{Ti}_2\text{N}$ MQDs

DFT calculations of the density of states (DOS) of a  $\text{Ti}_2\text{NO}_2$  MQD were performed as shown in Fig. 4A. The surface of the  $\text{Ti}_2\text{N}$  MXene or MQD requires functionalization by  $\text{O}_2$ ,  $-\text{OH}$ , or  $-\text{F}$  to be stabilized in structure.<sup>15,17</sup> In our case of MQDs in water environment,  $\text{O}_2$  is the most likely functional group of  $\text{Ti}_2\text{N}$  MQDs. We also conducted the calculation of band structure without  $\text{O}_2$  functionalization and found that Ti–O bonding



**Fig. 3** (A) PL spectra of  $\text{Ti}_2\text{N}$  MQDs with varying excitation wavelengths from 230 nm to 390 nm. (B) UV-Vis absorption and PLE spectra of  $\text{Ti}_2\text{N}$  MQDs. (C) PL spectra of  $\text{Ti}_2\text{C}$  MQDs with varying excitation wavelengths from 260 nm to 440 nm. (D) UV-Vis absorption and PLE spectra of  $\text{Ti}_2\text{C}$  MQDs. (E) Epifluorescence image of  $\text{Ti}_2\text{N}$  MQDs (scale bar = 20  $\mu\text{m}$ ). (F) The corresponding PL spectrum of thin film  $\text{Ti}_2\text{N}$  MQDs under 405 nm laser excitation.



**Fig. 4** DFT calculation results of 1.5 nm  $\text{Ti}_2\text{NO}_2$  (A) and  $\text{Ti}_2\text{CO}_2$  (B) MQDs. The valence band, conduction band, and higher-energy conduction band are denoted as  $E_0$ ,  $E_1$ , and  $E_2$ , respectively.

has a critical effect on the band structure of  $\text{Ti}_2\text{NO}_2$  MQDs (Fig. S9, ESI<sup>†</sup>). DOS calculations of  $\text{Ti}_2\text{NO}_2$  identified three energy bands of the valence band, conduction band, and higher-energy conduction band which are denoted as  $E_0$ ,  $E_1$ , and  $E_2$ , respectively. Normally, absorption occurs between  $E_0$  (N 2p) and  $E_1$  (Ti 3d) or  $E_0$  and  $E_2$  (Ti 3d) but PL is observed only by the transition between  $E_1$  and  $E_0$ .<sup>41,45–48</sup> We also observed a single peak PL around 3.0 eV and two absorption edges at 3.8 and 5.4 eV, which is consistent with the DFT calculation results discussed above. Furthermore, the values of  $E_1-E_0$  (3.8 eV) and  $E_2-E_0$  (5.3 eV) given by the calculated DOS are in good agreement with the observed PLE peaks. The almost constant PL peak position above 3.9 eV excitation observed in the excitation wavelength-dependent PL measurement in Fig. 3C is the result of the absorption from  $E_0$  to  $E_2$  and the consequent electron relaxation, followed by

exciton recombination at the conduction band edge. We observed a similar gradual redshift (blueshift) of the PL peak with increasing excitation wavelength (energy) due to the involvement of DOS at higher energy states within the conduction band ( $E_1$ ).<sup>17,28–30</sup> Additionally, we calculated the band structure of the  $\text{Ti}_2\text{NO}_2$  MQDs that were 3.0 nm in diameter (Fig. S8, ESI<sup>†</sup>), which showed a similar result, including the bandgap energy. This implies that varying the size of the MQDs is not an efficient way to tune the bandgap of the  $\text{Ti}_2\text{N}$  MQDs.

One interesting feature of the  $\text{Ti}_2\text{NO}_2$  quantum dots is the high PLE at high-energy excitation (5.4 eV) which is absent in  $\text{Ti}_2\text{CO}_2$ . To understand this feature, we further investigated the DOS of  $\text{Ti}_2\text{CO}_2$ . Three main differences in the DOS between  $\text{Ti}_2\text{NT}_x$  and  $\text{Ti}_2\text{CT}_x$  were observed. First, the Fermi level in  $\text{Ti}_2\text{NO}_2$  was located inside  $E_1$ , whereas it was in the gap between  $E_0$  and  $E_1$  in  $\text{Ti}_2\text{CO}_2$ . Second, the bandgap between  $E_0$  and  $E_1$  of

Ti<sub>2</sub>NO<sub>2</sub> was 0.5 eV larger than that of Ti<sub>2</sub>CO<sub>2</sub>. Third, the DOS of N (2p) and O (2p) states in Ti<sub>2</sub>NO<sub>2</sub> were strongly merged, inducing a strong absorption from E<sub>0</sub> to both E<sub>1</sub> and E<sub>2</sub> at 3.8 and 5.4 eV, respectively. In contrast, the DOS of the C (2p) and O (2p) states in Ti<sub>2</sub>CO<sub>2</sub> (Fig. 4B) were weakly merged and more dispersed over a large energy range. Consequently, the absorption from C (2p) to E<sub>1</sub> and E<sub>2</sub> (Ti (3d)) may appear at 3.3 and 4.3 eV, respectively, rather than in a higher energy range from O (2p) to E<sub>1</sub> and E<sub>2</sub>, explaining the absence of PLE at energies higher than 4 eV in Ti<sub>2</sub>CO<sub>2</sub>. Further symmetry analysis for the selection rules should be performed to clarify this scenario.

## 4. Conclusions

We fabricated light-emitting Ti<sub>2</sub>N MQDs that were water-soluble with a QY of 7.5%. TEM and AFM analyses showed that the MQDs maintained the crystal structure of the MXene and had an average diameter of 3.14 nm. The PLE and excitation energy-dependent PL measurements suggested that the bandgap was 3.8 eV and that the deep-UV absorption originated from the electronic transition to the higher-lying conduction band (E<sub>2</sub>). The optical properties of the nitride MQDs were compared with those of the carbide MQDs. Nitride MQDs exhibited more efficient UV absorption and emitted PL with higher energy excitation. DFT calculations of DOS confirmed the band structure suggested by the optical measurements. Our progress in the fabrication of light-emitting MQDs with a nitride-based MXene and improved understanding of the origin of light emission will expand the application of MQDs in optoelectronic devices.

## Conflicts of interest

The authors declare no competing financial interests.

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